

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Jiunn-Ren Hwang

Examiner: Ruggles, John S

.5

Anseime Chen

I-Hsiung Huang

Filing Date: 05/10/2001

Art Unit: 1756

Serial No.:

09/851,580

Docket No.: NAUP0292USA

10 Title: METHOD OF FORMING STORAGE NODES IN A DRAM

Assistant Commissioner of Patents

Washington, D.C. 20231

15 Subject:

Reply to the Office Action dated 03/11/2003

Dear Sir:

INTRODUCTORY COMMENTS

Do mod enter 20 Melf 5/3007 25

In response to the Office Action noted above, the above-identified application is to be amended as indicated in the following sections Consideration of all amendments is politely requested.

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